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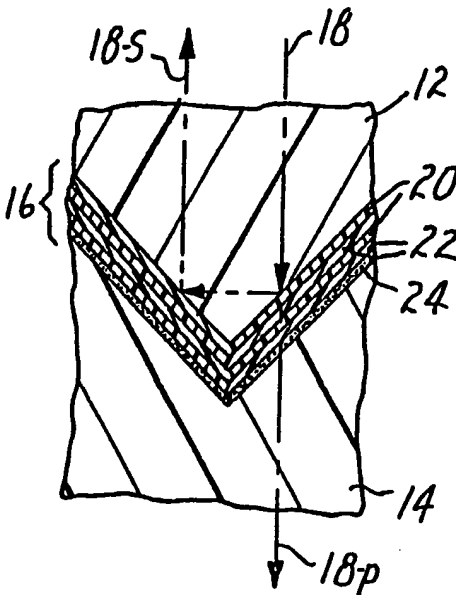
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## INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

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<p>(21) International Application Number: <b>PCT/US92/04271</b> (22) International Filing Date: <b>20 May 1992 (20.05.92)</b> (30) Priority data: <b>714,688</b>                      <b>13 June 1991 (13.06.91)</b>                      <b>US</b> (71) Applicant: <b>MINNESOTA MINING AND MANUFACTURING COMPANY [US/US]; 3M Center, P.O. Box 33427, Saint Paul, MN 55133-3427 (US).</b> (72) Inventor: <b>WEBER, Michael, F. ; P.O. Box 33427, Saint Paul, MN 55133-3427 (US).</b> (74) Agents: <b>FORREST, Peter, et al.; Office of Intellectual Property Counsel, Minnesota Mining and Manufacturing Company, Post Office Box 33427, Saint Paul, MN 55133-3427 (US).</b></p>		<p>(81) Designated States: <b>AT (European patent), BE (European patent), BR, CA, CH (European patent), DE (European patent), DK (European patent), ES (European patent), FR (European patent), GB (European patent), GR (European patent), IT (European patent), JP, KR, LU (European patent), MC (European patent), NL (European patent), SE (European patent).</b>  <b>Published</b> <i>With international search report. Before the expiration of the time limit for amending the claims and to be republished in the event of the receipt of amendments.</i></p>

(54) Title: RETROREFLECTING POLARIZER



## (57) Abstract

A retroreflecting polarizer (10), comprising optical thin films coated on a structured material (12, 14) divides an incident beam of light into polarized components (18-s, 18-p) transmitting one component (18-p) through the polarizer and reflecting the other (18-s) back to the source.

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## RETROREFLECTING POLARIZER

5 Technical Field

This invention relates to polarizing thin film stacks coated onto substrates having structured surfaces.

10 Background

A MacNeille polarizer comprises alternating repeating layers of a pair of thin film materials deposited on a bulk substrate material. The pair of thin film materials comprises one low refractive index  
15 material and one high refractive index material. The indices, called a MacNeille pair, are chosen such that, for a given angle of incidence of a light beam, the reflection coefficient for p-polarized light ( $r_p$ ) is essentially zero at each thin film interface. The  
20 angle at which  $r_p$  is zero is called the Brewster angle, and the formula relating the Brewster angle to the numerical values of the indices is called the MacNeille condition. The reflection coefficient for s-polarized light ( $r_s$ ) is non-zero at each thin film interface.  
25 Therefore, as more thin film layers are added, the total reflectivity for s-polarized light increases while the reflectivity for p-polarized light remains essentially zero. Thus, an unpolarized beam of light, incident upon the thin film stack, has some or all of  
30 the s-polarized components reflected while essentially all of the p-polarized component is transmitted.

Such a thin film stack is deposited on two general types of substrates, which then classifies the type of polarizer produced as either immersed or non-immersed.  
35 For example, if the thin films are deposited on a flat face which forms the hypotenuse side of a right angle

(Porro) prism, and bonded to the similar side of an identical prism, the polarizer is an immersed polarizer. If the thin films are bonded between two planar slabs of transparent media, the polarizer is a non-immersed polarizer. In general, a polarizer is non-immersed if the geometry of the bulk encapsulant does not affect the immersion constant  $n_i \sin(\theta_i)$  of the light beam in a thin film material  $m_i$ .

For either immersed or non-immersed polarizers, the p-polarization component of an incident light beam is transmitted, while the s-polarization component is reflected from the thin film stack at an angle equal to the angle of incidence. The total change in direction of the s-polarization component from the incident direction is  $90^\circ$  for cube polarizers and usually about  $60^\circ$  for slab polarizers. Thus, the s-polarization component is typically unavailable for further use, leading to a decrease in overall intensity of light available, unless additional optics are employed to redirect the s-polarization component. For example, U.S. Patent 4,913,529 (Goldenberg et al.) discloses a liquid crystal display (LCD) television projection system using two reflectors, a polarization rotator and a prism to recombine both components.

Such systems are undesirably large for use in many common visual display systems, such as overhead projectors, and especially in portable or laptop computer displays where a thin profile is desired.

### 30 Disclosure of Invention

The invention is a retroreflecting polarizer, comprising:

(a) a first material having a structured surface consisting of a linear array of substantially right angled isosceles prisms arranged side by side and

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having perpendicular sides which make an angle of approximately  $45^\circ$  with respect to the tangent to a smooth surface opposite the structured surface,

(b) a second material essentially like the first material,

(c) on the structured surface of at least one material, at least one optical stack of alternating layers of high and low refractive index materials of selected optical thicknesses; the first and second materials all optically cemented to form a single unit in which the refractive index of the first and second materials, and the refractive indices and optical thicknesses of the layers of the optical stack, are all chosen to produce selective reflection of polarized light, such that:

(d) within one portion of the optical stack, an incident light beam of mixed polarization is separated into an s-polarized component and a p-polarized component,

(e) the s-polarized component is reflected onto another portion of the optical stack and there reflected parallel to the incident beam but proceeding in an opposite direction, and

(f) the p-polarized component is transmitted parallel to the incident beam.

#### Brief Description of the Drawing

Figure 1 is a cross sectional view of a portion of one preferred embodiment of the invention.

Figure 2 is an enlarged sectional view of a portion of the embodiment of Figure 1.

Figure 3 is a schematic side view of an optical system employing the invention.

Figure 4 is a graph of the transmissivity and reflectivity of light incident upon one embodiment of the invention.

Detailed Description of the Invention

Figures 1 and 2 show an inventive retroreflecting polarizer 10, comprising two pieces of transparent substrate material 12 and 14, between which is a composite optical stack 16.

The pieces 12,14 each have structured surfaces (which face each other), and non-structured surfaces. As shown, piece 12 is a top layer and piece 14 is a substrate, but the entire assembly may be inverted with no loss of functionality, essentially interchanging the roles of the two pieces.

In the embodiment shown, the composite optical stack 16 is deposited upon the structured surface of the upper piece 12, and the structured surface of the lower piece 14 is optically cemented (i.e., adhered by a very thin layer of transparent adhesive) to the composite optical stack 16 by an adhesive 24 to form a single unit. However, the composite optical stack could comprise two sub-stacks, one sub-stack deposited on the top layer and the other deposited on the substrate, with adhesive 24 between the two sub-stacks.

The composite optical stack comprises at least one set of pairs of alternating layers of materials having low and high indices of refraction compared to each other. The thicknesses of the layers are chosen such that the quarterwave criterion is met for the wavelength of the incident collimated light beam 18 by each of layers 20 and 22. The shape of the structured surfaces, the optical properties of the substrate material, and the properties of the composite optical stack, all combine to divide the incident light beam into two polarization components. One component, 18-s, is reflected twice in such a manner as to be retroreflected, i.e., directed back toward the source of light beam 18. The other component, 18-p, is transmitted parallel to incident beam 18.

(In Figure 2, the division of incident light 18 into components 18-s and 18-p is shown as occurring at the first interface between the substrate and the composite optical stack, but this is illustrative only.

5 Actually, some division occurs at each interface between thin films, with the net result being as shown.)

In the embodiment shown, the composite optical stack comprises a repeating stack of a pair of  
10 materials. One of the materials is a relatively low refractive index ( $n_L$ ) material 20, and the other is a relatively high index ( $n_H$ ) material 22. The construction of such a stack 16 is abbreviated  $(HL)^2$ . In general, more layers are used, such as a  $(HL)^5$  stack,  
15 and generally the average optical thickness of each material is a quarterwave thick, with reference to a chosen wavelength of interest (typically but not necessarily in the visible spectrum). However, to  
optimize performance, the individual thicknesses of all  
20 thin film layers are varied slightly from the average thickness, in accordance with known principles, using commercially available software to calculate the desired values.

Also, more than two pairs of materials or average  
25 thicknesses may be used, such as a  $(H_1L_1)^5 + (H_2L_2)^5$ . This would be done to extend the useful optical bandwidth of the invention or the range of angles over which the invention reflects essentially all s-polarized light.

Each of substrate pieces 12 and 14 comprises a  
30 transparent, preferably integral (i.e., a single continuous piece as opposed to an assembly or a laminate) material having a structured surface which consists of a linear array of substantially right angled isosceles prisms arranged side by side. The  
35 perpendicular sides of each prism make an angle of approximately  $45^\circ$  with respect to the smooth surface



opposite the structured surface (or, in the most general case of a flexible substrate, with respect to the tangent to the structured surface). Angles other than 45° are useful for other applications, but angles  
5 near 45° (e.g., 40° to 50°) are preferred in this invention. This places a constraint on the design of the optical stack: only two of the three indices of refraction ( $n_L$  and  $n_H$  for the optical stack,  $n_0$  for the substrate pieces) can be chosen independently. (An  
10 additional implication is that  $n_L$  must always be less than  $n_0$  if high transmission of p-polarized light is desired at all wavelengths.) These values are determined by the MacNeille condition relating the Brewster angles of each material interface to the  
15 numerical values of the indices of the materials forming the interface:

$$\tan(\theta_L) = (n_H/n_L)$$

or,

20

$$\tan(\theta_H) = (n_L/n_H)$$

along with Snell's law relating  $\theta_0$  to  $\theta_L$  and  $\theta_H$ .

25 In theory, an infinite set of values of  $n_H$  and  $n_L$  exist for a given  $n_0$ , but in practice, the available choices of materials for the substrate pieces and thin films are limited, and design of the invention reduces to choosing which of the limited set of values of  $n_H$   
30 and  $n_L$  around that value of  $n_0$  will produce the desired results. The greater the difference between  $n_L$  and  $n_H$ , the wider the optical bandwidth over which the invention will divide incident light into separate polarizations.

35 A suitable thickness of the substrate is 0.36 millimeters, measured from the smooth surface to the

lowest point of the grooves. Suitable groove heights (measured perpendicularly) are 0.18 mm. For such a film, about 28 peaks per centimeter is preferred, but there is wide latitude in the dimensions.

- 5 Preferred substrate materials are flexible, homogeneous, and isotropic. Suitable materials include commercially available acrylics and polycarbonates having nominal indices of refraction of 1.49 and 1.59, respectively. Other possible materials, selected to
- 10 provide the required functionality, include polypropylenes, polyurethanes, polystyrenes, and polyvinylchlorides. Generally, polycarbonates are preferred for their relatively high indices of refraction, clarity, and physical properties.
- 15 Higher index materials include polysulphone (and variations such as polyethersulphone and polyarylsulphone), polyethylene terephthalate (PET), and polyethylene naphthalate (PEN). The sulphones require high processing temperatures, but in turn can
- 20 withstand higher ambient temperatures in use. PET and PEN may crystallize or exhibit birefringence depending on the process parameters. All these materials have indices in the range of 1.63 to 1.65, and as such, allow the use of the film pair  $\text{SiO}_2/\text{TiO}_2$  while retaining
- 25 high transmission of p-polarized light.

A suitable material is taught in U.S. Patent 4,805,984 (Cobb, Jr.), but in this invention the total internal reflection property of that material is not relevant, because the optical properties of the

30 material are significantly changed when it is employed in this invention.

Suitable materials for the thin films 20 and 22 include any materials which are transparent (exhibit low absorption) in the spectrum of interest. For

35 broadband visible light, suitable thin film materials are silicon dioxide ( $\text{SiO}_2$ ) ( $n=1.45$ ); amorphous

hydrogenated silicon nitride ( $a\text{-SiN:H}$ ) ( $n=1.68\text{--}2.0$ ); titanium dioxide ( $\text{TiO}_2$ ) ( $n=2.2\text{--}2.5$ ); magnesium fluoride ( $\text{MgF}_2$ ) ( $n=1.38$ ); cryolite ( $\text{Na}_3\text{AlF}_6$ ) ( $n=1.35$ ); zinc sulphide ( $\text{ZnS}$ ) ( $n=2.1\text{--}2.4$ ); zirconium oxide ( $\text{ZrO}_2$ ) ( $n=2.05$ ); hafnium oxide ( $n=2.0$ ); and aluminum nitride ( $n=2.2$ ). Silicon nitride ( $\text{Si}_3\text{N}_4$ ) is suitable, but has not been formed successfully on the preferred polycarbonate substrate.

Several thin film deposition techniques can be used to deposit the composite optical stack on the substrate. Thermal and electron beam evaporation, and ion beam sputtering are the methods of choice for precision optical coatings, the latter method producing superior films in terms of adhesion to the substrate, hardness, and environmental stability. Magnetron sputtering is also used extensively for broadband coatings such as anti-reflective coatings on glass, and especially for large area applications such as architectural glass. However, on the whole, thermal and electron beam evaporation should provide good thin film qualities and sufficiently high deposition rates for acceptable manufacturing rates. More importantly, low index films such as magnesium fluoride and cryolite can be deposited by this method. Electron beam deposition is regularly used in the coatings industry for high index materials such as titanium dioxide, zirconium oxide, hafnium oxide, and aluminum nitride.

The process used in the reduction to practice of the invention was plasma assisted chemical vapor deposition (PACVD). Using this PACVD, the following procedures and resultant products are possible.

$\text{SiO}_2$  may be deposited by reacting silane ( $\text{SiH}_4$ ) or almost any organosilane in the PAVCD process with oxygen or nitrous oxide at between 50 and 250 milliTorr, using low power RF plasmas of about 50-100 watt/ft<sup>2</sup> of electrode area. Nitrous oxide is somewhat

preferred because it generally results in less powder formations in the gas phase.

TiO<sub>2</sub> may be formed by reacting titanium tetrachloride (TiCl<sub>4</sub>) with oxygen and nitrous oxide at the same power levels. By varying both the relative and absolute flow rates of the O<sub>2</sub> and N<sub>2</sub>O for a given flow of TiCl<sub>4</sub> vapor, the index of refraction of the film is easily varied, from 2.0 to 2.4. Residual chlorine in the film can result in poor adhesion to polycarbonate. An oxygen flow of several times in excess of the reactant gas is preferred.

The visibly transparent a-SiN:H material has an index of refraction which varies mainly as a function of deposition temperature, with the higher indices requiring temperatures of 250 Celsius or more. The films may be deposited from mixtures of silane, ammonia, and nitrogen. Films formed at lower temperatures from conditions suitable for high index films (i.e., silane, starved nitrogen, no ammonia) produce undesirably high absorption of blue light. It is possible to form films having indices between 1.68 and 1.8 on polycarbonate below 100 C, with low optical absorption, although the lower index films are somewhat brittle.

The PACVD process was carried out using a deposition system according to the teachings of U.S. Patents 4,841,908 and 4,874,631 (Both Jacobson, et al.). Briefly, this multi-chamber deposition system employs a large volume vacuum chamber within which are plurality of deposition chambers for different composition layers, each chamber having separate seals to minimize back diffusion of any dopant gases from adjacent deposition chambers. A continuous roll of substrate proceeds from a supply roll through each of the deposition chambers and onto a finished take-up roll. The direction of web travel is reversed

repeatedly to produce the multiple layers of repeating refractive index materials.

The index of refraction ( $n_A$ ) of the adhesive 24 should match that of the upper and lower pieces 12 and 5 14 as closely as possible. When the index of the adhesive is less than that of the adjoining piece, the non-zero thickness of the adhesive leads to some refraction of light away from the original beam direction. Adhesives of  $n_A = 1.56$  are available from 10 the Norlund Company. Suitable adhesives are Norlund numbers 61 and 81 optical cements ( $n_A = 1.56$ ). Another ultraviolet curable resin ( $n_A = 1.50$ ) can be made from Union Carbide number ERL 4221 epoxy resin with 1% (by weight) Minnesota Mining and Manufacturing Company 15 number 41-4201-91185 sulphonium salt initiator. The initiator is dissolved in methylene chloride which must be evaporated off before mixing with the epoxy. Other UV curable mixtures, not as preferred, may be made from urethane acrylate base resins, diacrylate diluents, and 20 suitable photoinitiators. UV curable adhesives may cause slight absorption, mainly in the blue end of the spectrum, in the completed polarizer of about 1-2%. Any thermosetting adhesive or epoxy will work also provided it has low optical absorption and high index.

25

#### Example

Alternating thin film layers of matched quarterwave optical thickness were coated on the structured side of a 14 mil thick polycarbonate version 30 of the preferred substrate material described in U.S. Patent 4,805,984 (Cobb, Jr.) In Example 1, coating was done by the plasma assisted chemical vapor deposition (PACVD) process described above, using a 5 inch wide and 8 inch long gas "showerhead" type 35 electrode. To form the retroreflective polarizer, an

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uncoated piece of the TIR material was adhered to the optical stack with an optical adhesive.

In Example 1, the polarizer had three optical stacks, each having twelve layers, either silicon dioxide ( $\text{SiO}_2$ ) or titanium dioxide ( $\text{TiO}_2$ ). The unusually high number of layers was required because the PACVD technique as described above did not produce a uniform film thickness near the prism peaks as opposed to the bottoms of the grooves. The first stack had a quarterwave thickness centered at 400 nm, the next centered at 550 nm, the third centered at 700nm. The polarizer performance is shown in Figure 4. Transmissivity of the s-polarization component,  $T(s)$ , was at or near zero throughout nearly all the visible spectrum, while reflectivity of that component,  $R(s)$ , approached the 95% level typical of the most efficient common reflectors. Transmissivity of the p-polarization component,  $T(p)$ , was very acceptable, nearly 80% or more throughout the visible spectrum.

It is useful to provide a few details of the angular dependence of the retroreflecting polarizer. The first feature is the angular dependence of transmission for p-polarized light, through one prism facet. The angle  $\theta$  is measured in air from the unit vector normal to the outside surface of the retroreflecting polarizer. The assumed film stack is a combination of three stacks designed to cover the visible spectrum at all angles of incidence. The transmission spectrum vs. angle is broader at longer wavelengths ( $\pm 45^\circ$  at 650 nm). This stack comprises twenty-eight layers: an eight layer stack centered at 600 nm and  $45^\circ$  (immersed), along with a double stack, of ten layers each, designed for  $15^\circ$ , with center wavelengths of 450 and 600 nm.

The computer calculated angular dependence of transmission, for a wavelength of 450 nm, shows an asymmetry of p-polarized transmission for positive and

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negative values of theta. This arises from the inclination of the prism facets at 45° from the substrate surface, whereas the angle theta is measured in air from the normal to the outside surface. Total  
5 transmission through the polarizer is the sum of two transmissions, at complimentary angles, through two opposing facets. When both terms are taken into account, the transmission curve is symmetrical. Tertiary and higher order reflections from light  
10 transmitted laterally at the second prism can be accounted for as well, but do not have a great impact on the shape of the curve.

#### Applications

15 The invention is suitable for applications requiring polarized light that would benefit from increasing the intensity of the polarized light available from an unpolarized source, and especially those requiring polarized light over relatively large  
20 areas and/or in relatively compact (especially thin) applications.

For example, the inventive retroreflecting polarizer can be combined in a very simple manner with a quarterwave retardation plate and a reflector to  
25 recombine the two components of an incident light beam into a single polarized component of light. Such an arrangement is shown in Figure 3. A combined reflector and source of incident light 118 is illustrated schematically as 130. Incident light 118, having mixed  
30 polarization, is not affected by quarterwave retardation plate 120, but is split into components 118-p and 118-s by retroreflecting polarizer 100. Component 118-p is transmitted directly to display device 110. Component 118-s is retroreflected back  
35 through a quarterwave retardation plate 120 as shown by 119, and reflected (and displaced transversely upward for clarity as component 121) back through the

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quarterwave retardation plate again as shown by 121. The two passes through the quarterwave retardation plate represent a total rotation of  $90^\circ$ , i.e., component 118-s now has the same polarization direction  
5 as component 118-p, and is also directed toward display device 110, thus nearly all of the intensity of incident unpolarized light 118 is available in polarized form at display device 110.

The great advantage of the invention in this  
10 system is that because all components may be relatively thin and large in area, and lie on essentially the same optic axis, the profile of the system can be greatly reduced. Where reduction in profile is not as much a concern, or where convenient for other reasons, the  
15 optic axis can be redirected without loss of generality.

Reflecting source 130 may be the light source of a backlit computer display, or an overhead projector such as models widely available from the Minnesota Mining  
20 and Manufacturing Company. Display device 110 may be a group of one or more birefringent LCD panels, employed in monochrome or color applications, such as those disclosed in U.S. Patents 4,917,465 (Conner et al.) and 4,966,441 (Conner).

25 For this application, assuming a polycarbonate substrate of index  $n_0 = 1.586$ , the ideal thin film indices are  $n_H = 2.0$  and  $n_L = 1.35$ . With this pair of indices, the theoretical minimum composite optical stack for a photoptic (i.e., covering the entire  
30 visible spectrum) retroreflecting polarizer is two sets of eight layers, i.e.,  $(HL)^4 + (H'L')^4$ . One set has a bandwidth centered on 425 nm and the other has a bandwidth centered on 650 nm. Although cryolite has the most desired low index ( $n_L = 1.35$ ), it is soft and  
35 slightly hygroscopic, so magnesium fluoride ( $n_L = 1.38$ ) is preferred. Zirconium oxide ( $n_H = 2.05$ ) is one



preferred high index material, although several other materials are suitable.

I claim:

1. A retroreflecting polarizer, comprising:

5

(a) a first material having a structured surface consisting of a linear array of substantially right angled isosceles prisms arranged side by side and having perpendicular  
10 sides which make an angle of approximately  $45^\circ$  with respect to the tangent to a smooth surface opposite the structured surface,

(b) a second material essentially like the first material,

15

(c) on the structured surface of at least one material, at least one optical stack of alternating layers of high and low refractive index materials of selected optical thicknesses;

20

the first and second materials all optically cemented to form a single unit in which the refractive index of the first and second materials, and the refractive indices and optical thicknesses of the layers of the optical stack, are all chosen  
25 to produce selective reflection of polarized light, such that:

30

(d) within one portion of the optical stack, an incident light beam of mixed polarization is separated into an s-polarized component and a p-polarized component,

35

(e) the s-polarized component is reflected onto another portion of the optical stack and there reflected parallel to the incident beam but proceeding in an opposite direction, and

(f) the p-polarized component is transmitted parallel to the incident beam.

2. An optical system comprising, along a common optic axis:

- 5 (a) a source of incident light of mixed polarization;
- (b) a reflector;
- (c) a quarterwave retardation plate;
- (d) the retroreflecting polarizer of claim 1;
- 10 (e) a display device employing polarized light;

15 in which the p-polarized component is transmitted to the display device, and the s-polarized component passes through the quarterwave retardation plate to the reflector, returning through the quarterwave retardation plate to become a second p-polarized component before proceeding to the display device.

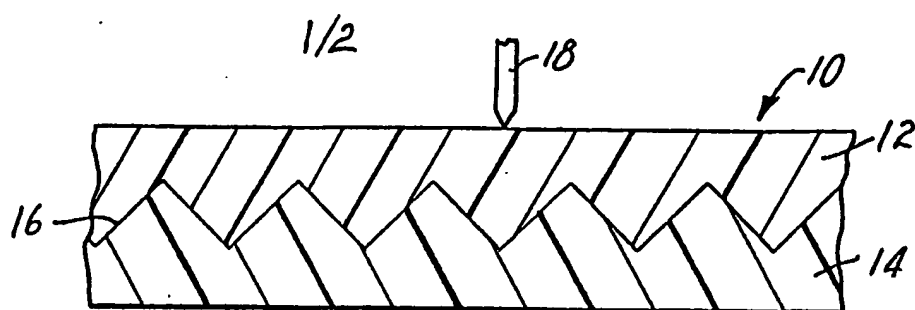


FIG. 1

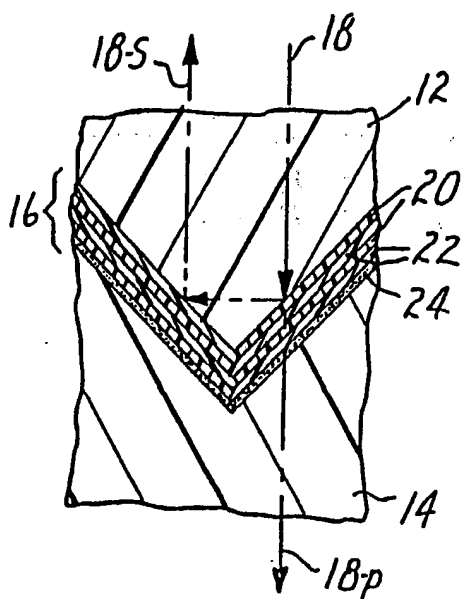


FIG. 2

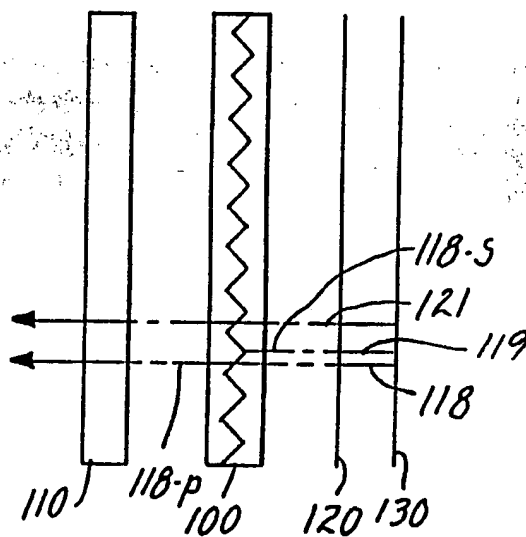


FIG. 3

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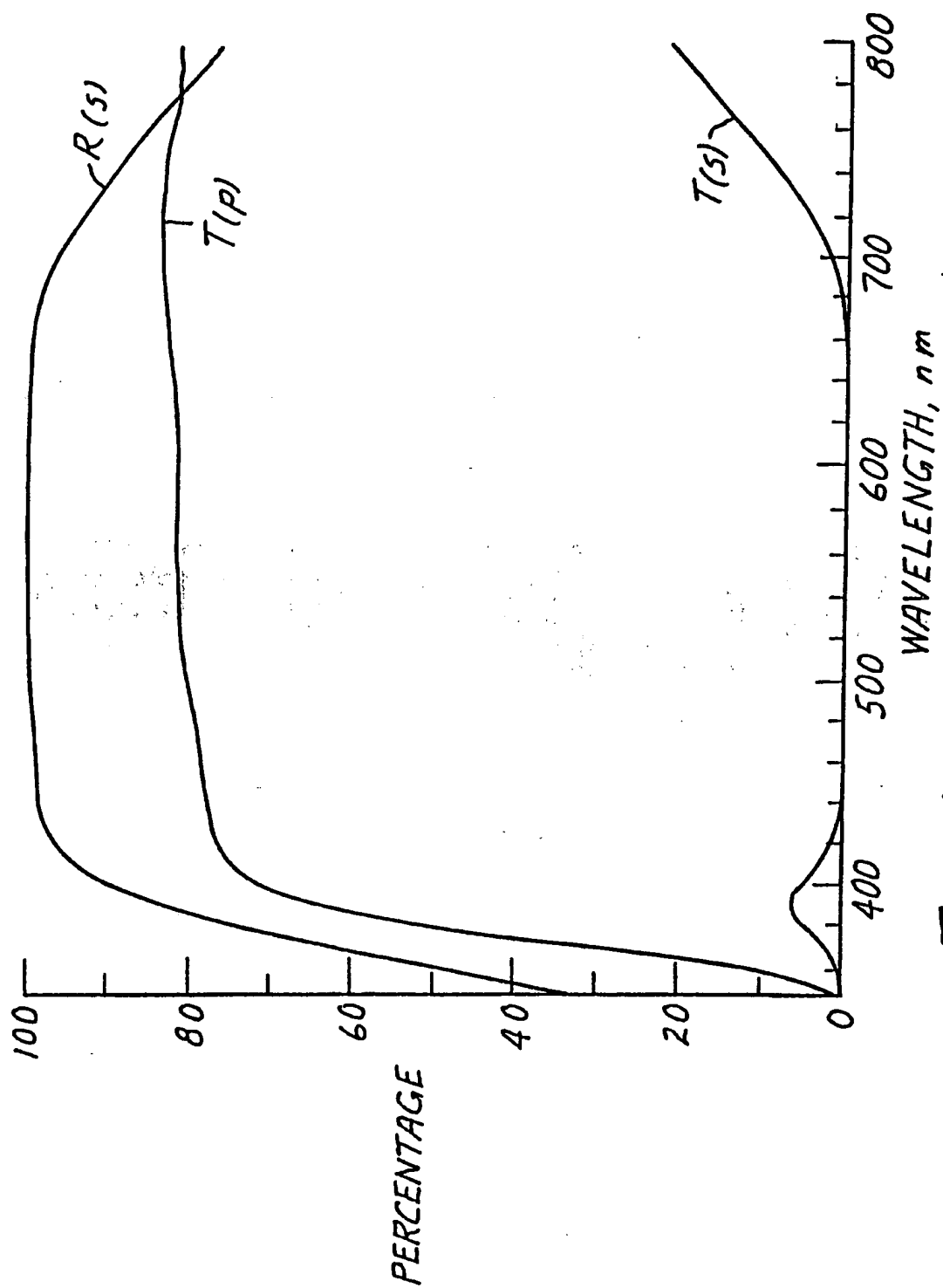
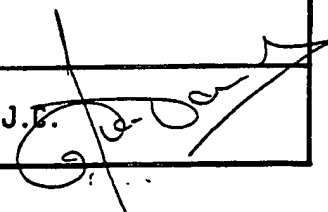


FIG. 4

## INTERNATIONAL SEARCH REPORT

PCT/US 92/04271

International Application No

<b>I. CLASSIFICATION OF SUBJECT MATTER</b> (if several classification symbols apply, indicate all) <sup>6</sup>		
According to International Patent Classification (IPC) or to both National Classification and IPC		
Int.Cl. 5 G02B5/30; G02B5/122		
<b>II. FIELDS SEARCHED</b>		
Minimum Documentation Searched <sup>7</sup>		
Classification System	Classification Symbols	
Int.Cl. 5	G02B	
Documentation Searched other than Minimum Documentation to the Extent that such Documents are Included in the Fields Searched <sup>8</sup>		
<b>III. DOCUMENTS CONSIDERED TO BE RELEVANT<sup>9</sup></b>		
Category <sup>10</sup>	Citation of Document, <sup>11</sup> with indication, where appropriate, of the relevant passages <sup>12</sup>	Relevant to Claim No. <sup>13</sup>
A	DE,A,2 137 422 (HORST BÄHRING) 8 February 1973 see claims 1,5,6; figures 5,6 see page 6, line 22 - line 34 ---	1
A	EP,A,0 285 397 (SPECTRA-PHYSICS INC.) 5 October 1988 see abstract; claims 1-6; figures 2,3 ---	1
A	EP,A,0 390 344 (MINNESOTA MINING AND MANUFACTURING COMPANY) 3 October 1990 see abstract; claims 1,2 ---	1
A	PATENT ABSTRACTS OF JAPAN vol. 10, no. 298 (P-505) <sup>9</sup> October 1986 & JP,A,61 114 205 ( NIPPON CERAMIC KK ) see abstract -----	1
<p><sup>10</sup> Special categories of cited documents:</p> <p>"A" document defining the general state of the art which is not considered to be of particular relevance</p> <p>"E" earlier document but published on or after the international filing date</p> <p>"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified)</p> <p>"O" document referring to an oral disclosure, use, exhibition or other means</p> <p>"P" document published prior to the international filing date but later than the priority date claimed</p> <p>"T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention</p> <p>"X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to involve an inventive step</p> <p>"Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art.</p> <p>"&amp;" document member of the same patent family</p>		
<b>IV. CERTIFICATION</b>		
Date of the Actual Completion of the International Search		Date of Mailing of this International Search Report
16 OCTOBER 1992		30. 10. 92
International Searching Authority		Signature of Authorized Officer
EUROPEAN PATENT OFFICE		VAN DOREMALEN J.E. 

**ANNEX TO THE INTERNATIONAL SEARCH REPORT  
ON INTERNATIONAL PATENT APPLICATION NO. US 9204271  
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